



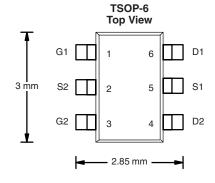
# **Dual P-Channel 8-V (D-S) MOSFET**

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
- 8	0.125 at V <sub>GS</sub> = - 4.5 V	± 2.5		
	0.175 at V <sub>GS</sub> = - 2.5 V	± 2.0		
	0.265 at V <sub>GS</sub> = - 1.8 V	± 1.7		

### **FEATURES**

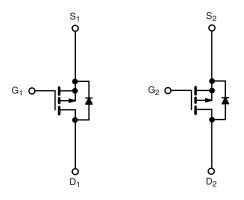
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET<sup>®</sup> Power MOSFETs: 1.8 V Rated
- Compliant to RoHS Directive 2002/95/EC





Ordering Information: Si3905DV-T1-E3 (Lead (Pb)-free)

Si3905DV-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T <sub>A</sub> = 25 °C, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	- 8	V	
Gate-Source Voltage		V <sub>GS</sub>	± 8	V	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a, b</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub>	± 2.5		
Continuous Drain Current (1, = 150 °C)	T <sub>A</sub> = 70 °C		± 2.0		
Pulsed Drain Current		I <sub>DM</sub>	± 7	A	
Continuous Diode Current (Diode Conduction) <sup>a, b</sup>		I <sub>S</sub>	- 1.05		
	T <sub>A</sub> = 25 °C	P <sub>D</sub>	1.15	- w	
Maximum Power Dissipation <sup>a, b</sup>	T <sub>A</sub> = 70 °C	] 'D	0.73		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Marrian un lun ation to Analogo til	t ≤ 5 s	R <sub>thJA</sub>	93	110	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		130	150	
Maximum Junction-to-Lead	Steady State	R <sub>thJL</sub>	75	90	

Notes:

a. Surface Mounted on FR4 board.

b.  $t \le 5$  s.

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SPECIFICATIONS T <sub>J</sub> = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	s Min.		Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	- 0.45			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = - 6.4 V, V <sub>GS</sub> = 0 V			- 1		
		$V_{DS} = -6.4 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			- 5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \le$ - 5 V, $V_{GS} =$ - 4.5 V	- 5			Α	
		$V_{GS} = -4.5 \text{ V}, I_D = -2.5 \text{ A}$		0.103	0.125		
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -2.5 \text{ V}, I_D = -2.0 \text{ A}$		0.146	0.175	Ω	
		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 1 A		0.205	0.265		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 4.5 V, I <sub>D</sub> = - 2.5 A		5.3		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = -1.05 \text{ A}, V_{GS} = 0 \text{ V}$		- 0.79	- 1.1	V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_g$			4.2	6	nC	
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -2.5 \text{ A}$		0.45			
Gate-Drain Charge	$Q_{gd}$			0.90			
Turn-On Delay Time	t <sub>d(on)</sub>			10	15		
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 5 V, $R_L$ = 5 $\Omega$		47	70		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong$ - 1 A, $V_{GEN}$ = - 4.5 V, $R_g$ = 6 $\Omega$		28	45	ns	
Fall Time	t <sub>f</sub>			34	50		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 1.05 A, dl/dt = 100 A/μs		20	40		

#### Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.

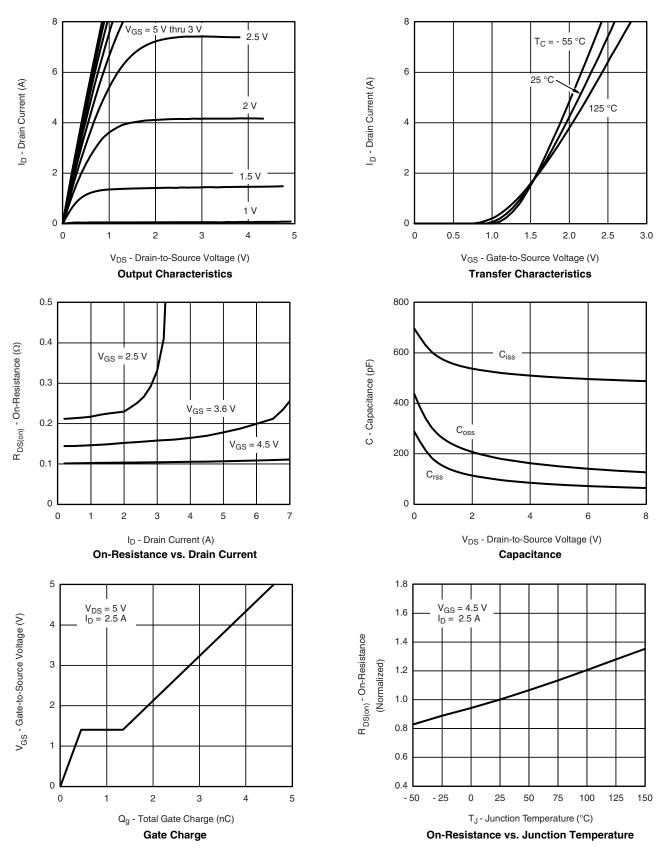
b. Guaranteed by design, not subject to production testing.







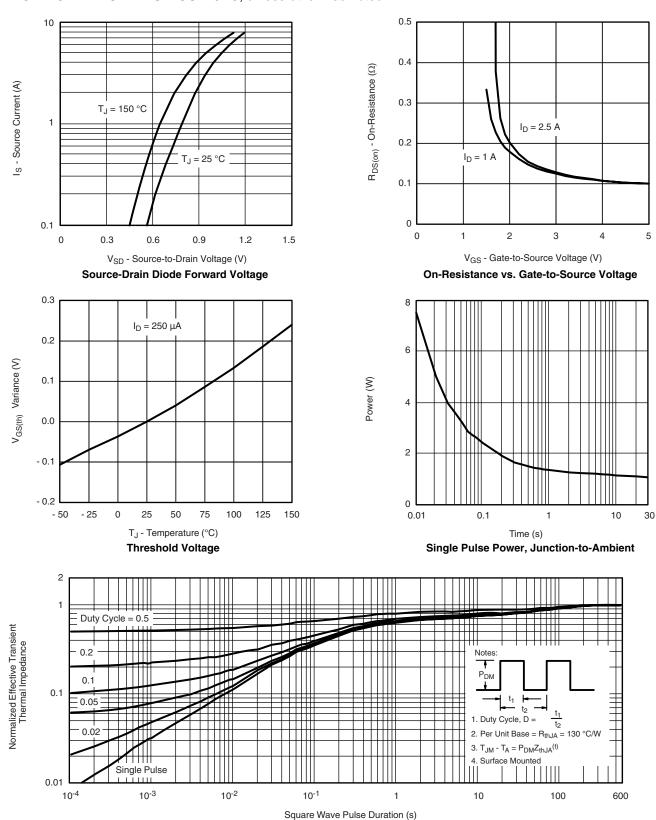
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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# VISHAY

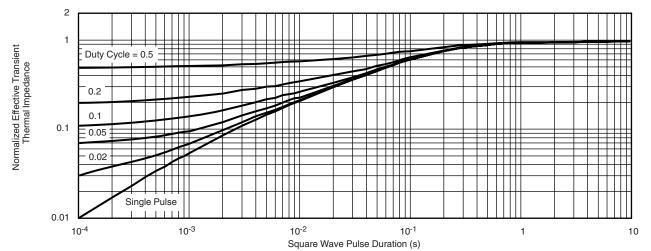
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





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### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?70973">www.vishay.com/ppg?70973</a>.



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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